

Technical Data Sheet

Side Face Infrared LED

Features

- High reliability
- High radiant intensity
- Peak wavelength λ p=940nm
- 2.54mm Lead spacing
- Low forward voltage
- Pb free
- This product itself will remain within RoHS compliant version.

Descriptions

- EVERLIGHT's Infrared Emitting Diode (IR908-7C) is a high intensity diode, molded in a water clear plastic package.
- The miniature side- facing device has a chip, that emits radiation from the side of the clear package.

Applications

- Mouse
- Optoelectronic switch
- Infrared applied system

Device Selection Guide

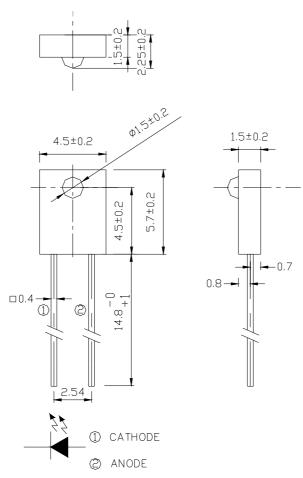
LED Part No.	Chip Material	Lens Color	
IR908-7C	GaAlAs	Water clear	

IR908-7C



Package Dimensions

IR908-7C



Notes: 1.All dimensions are in millimeters 2.Tolerances unless dimensions ±0.25mm

Absolute Maximum Ratings (Ta=25°C)

Parameter	Symbol	Rating	Units
Continuous Forward Current	$I_{\rm F}$	50	mA
Peak Forward Current	I _{FP}	1.0	А
Reverse Voltage	V_R	5	V
Operating Temperature	T _{opr}	-25 ~ +85	°C
Storage Temperature	T _{stg}	-40 ~ +100	°C
Soldering Temperature	T _{sol}	260	°C
Power Dissipation at(or below) 25°C Free Air Temperature	P _d	75	mW

Notes: *1:I_{FP} Conditions--Pulse Width $\leq 100 \,\mu$ s and Duty $\leq 1\%$.

*2:Soldering time \leq 5 seconds.



<u>IR908-7C</u>

Electro-Optical Characteristics (Ta=25°C)

Parameter	Symbol	Condition			Mi	in.	Typ.	Max.	Units	
Light Current	Ic(on)	$I_F=4mA, V_{CE}=3.5V$				14	13		1274	μ A
Peak Wavelength	λρ		I _F =20m	А		-	-	940		nm
Spectral Bandwidth	Δλ	I _F =20mA				-	-	45		nm
Forward Voltage	V _F	I _F =20mA				-	-	1.2	1.5	V
Reverse Current	I _R	V _R =5V				-	-		10	μA
View Angle	2 0 1/2	I _F =20mA			-	-	60		De g	
Rank										
Color Code	Ranks	Symbol	Min	Тур	Ма	ax	Ur	nit	Test Condition	
Red	E1	Ic(on)	143		25	5	μ	A j	_F =4mA,	V _{CE} =3.5V
Blue	E2	Ic(on)	214		34	3	μ	A]	_F =4mA,	V _{CE} =3.5V
Yellow	E3	Ic(on)	286		43	1	μ	A]	_F =4mA,	V _{CE} =3.5V
Silver	E4	Ic(on)	357		51	9	μ	A]	_F =4mA,	V _{CE} =3.5V
Green	E5	Ic(on)	428		60	8	μ	A]	I_F =4mA, V_{CE} =3.5V	
Purple	E6	Ic(on)	500		69	6	μ	A]	I_F =4mA, V_{CE} =3.5V	
White	E7	Ic(on)	571		78	4	μ	A I	_F =4mA,	V _{CE} =3.5V

Rough ranks

Parameter	Min	Max	Unit	Test Condition
7-2	306	441	μA	I_F =4mA, V_{CE} =3.5V
7-1	347	550	μA	$I_F=4mA, V_{CE}=3.5V$
6-2	465	750	μA	$I_F=4mA, V_{CE}=3.5V$
6-1	650	1274	μA	I_F =4mA, V_{CE} =3.5V

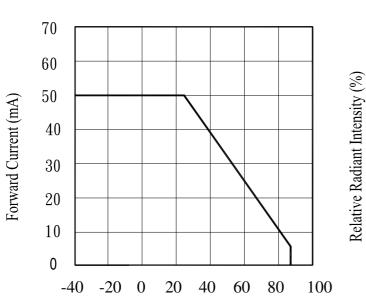


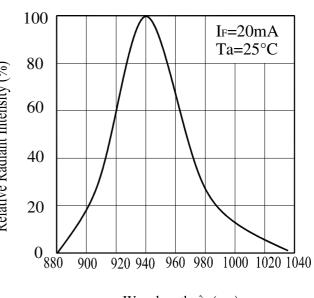
Typical Electro-Optical Characteristics Curves

Ambient Temperature

Fig.1 Forward Current vs.

Fig.2 Spectral Distribution

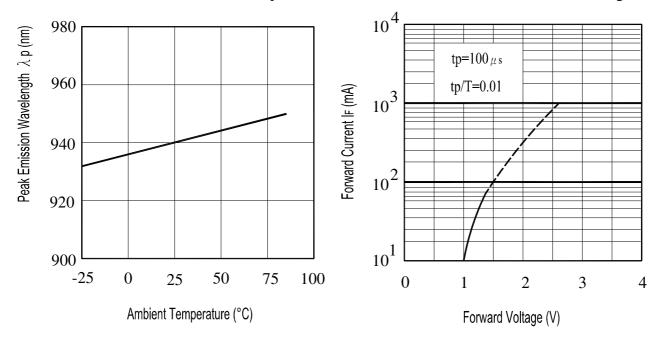




Wavelength λ (nm)

Fig.3 Peak Emission Wavelength vs. Ambient Temperature Fig.4 Forward Current vs.

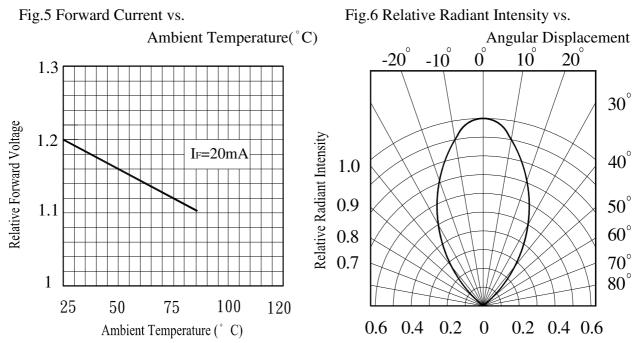
Forward Voltage



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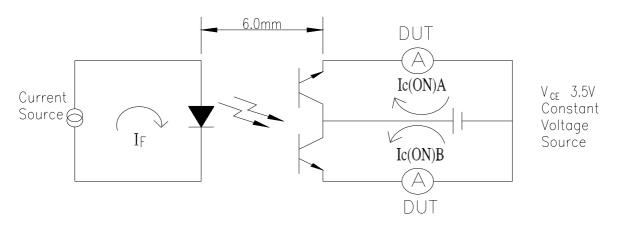
Typical Electro-Optical Characteristics Curves



Test Method For I_{C(ON)}:

Condition: $I_F=4mA, V_{CE}=3.5V$

The intensity testing method for infrared emitting diode



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Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level : 90%

LTPD: 10%

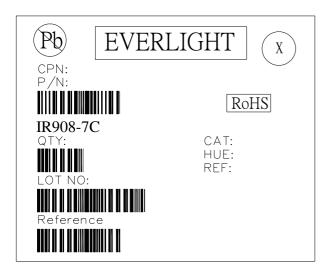
NO.	Item	Test Conditions	Test Hours/	Sample	Failure	Ac/Re
			Cycles	Sizes	Judgement	
					Criteria	
1	Solder Heat	TEMP. ∶ 260°C±5°C	10secs	22pcs		0/1
2	Temperature Cycle	H : +100°C 15mins	300Cycles	22pcs		0/1
		5mins				
		L : -40°C 15mins				
3	Thermal Shock	H :+100°C ▲ 5mins	300Cycles	22pcs		0/1
		▼ 10secs				
		$L:-10^{\circ}C$ 5mins			Attenuation of	
4	High Temperature	TEMP. ∶ +100°C	1000hrs	22pcs	Light Current	0/1
	Storage				value>20%	
5	Low Temperature	TEMP. ∶ -40°C	1000hrs	22pcs		0/1
	Storage					
6	DC Operating Life	I _F =20mA	1000hrs	22pcs		0/1
7	High Temperature/	85°C / 85% R.H	1000hrs	22pcs		0/1
	High Humidity					



Packing Quantity Specification

- 1. 1000PCS/1Bag,8Bag/1Box
- 2. 10Boxes/1Carton

Label Form Specification



CPN: Customer's Production Number P/N : Production Number QTY: Packing Quantity CAT: Ranks HUE: Peak Wavelength REF: Reference LOT No: Lot Number X: Month Reference: Identify Label Number

Notes

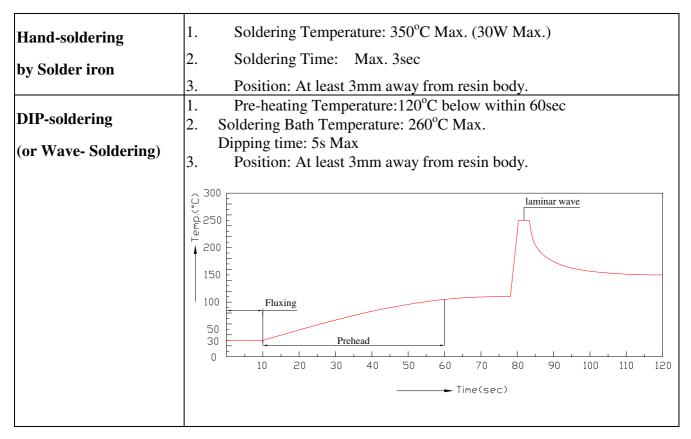
- 1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
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Application Note:

Through-Hole Type LED Soldering Condition

To avoid overheating and reliability concerns of through-hole type LEDs, below is our suggested soldering method :



Notice:

- 1. Avoiding applying any stress to the lead frame while the LEDs are at high temperature particularly when soldering.
- 2. Dip and hand soldering should not be done more than 1 time.
- 3. After soldering the LEDs, the epoxy resin should be protected from mechanical shock or vibration until the LEDs return to room temperature.



<u>IR908-7C</u>

- 4. A rapid-rate process is not recommended for cooling the LEDs down from the peak temperature.
- 5. Although the recommended soldering conditions are specified in the above table, dip or hand-soldering at the lowest possible temperature is desirable for the LEDs.
- 6. Wave soldering parameter must be set and maintain according to recommended temperature and dwell time in the solder wave.

Cleaning

- 1. When necessary, cleaning should only use with isopropyl alcohol at room temperature for a duration of no more than 1 minute. Dry at room temperature before use.
- 2. Do not clean the LEDs by the ultrasonic. When it is absolutely necessary, the influence of ultrasonic cleaning on the LEDs depends on factors such as ultrasonic power and the assembled condition. (Please refer to below reference condition.)
 - Notice: (1) This bonding wire in the package can have an effect on the resonance reliability.
 - Please not touch the vibrating source directly. Ultrasonic cleaning shall be pre-qualified to ensure this will not cause damage to the LED
 - (2) Reference condition: Refer to JEITA Standard Test requirement
 - a. Ultrasonic Wave Frequency: 25KHz±4KHz or 40 KHz (+8 KHz/-4KHz)
 - b. Output: 10W/Litre ~30W/Litre
 - c. Duration: 60s±5S, Temperature: under 40°C

Drying should be performed under 90°C and 30s.

Both cleaning and Drying should not be performed over 4 times.

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